

A New Single Phase PV fed Five Level Inverter Topology connected to the Grid

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Presentation By

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The Journey of Thousand Miles Begins with a single step





To design a new Multilevel Inverter Topology for Photovoltaic Applications with minimum number of Switches

To Design a Control algorithm for New Topology with minimum carrier signals

To suggest a Novel Carrier for Multilevel inverters

To compare the novel carrier with Conventional Triangular Carrier (Comparison based on Ma and Mf with THD)





Low aim is a crime- Diode-John Ambrose Fleming-1904



PHOTOVOLTAIC CELL WORKING PRINCIPLE







Model a Drop, To know the power of the OCEAN- Zener Diode –Clarence Melvin Zener-1915







From the figure

$$I = I_L - I_D - - - -(1)$$

Where I=Output Current In Amps I₁=light Current Or Photo Generated Current In Amps I_D= Diode Current in amps



Workship the creator not his creation- Edmond Becquerel ,1889 Electricity From Sun



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By Shockley equation, current diverted through diode is

$$I_D = I_o \left[\exp\left(\frac{U + IR_s}{nkT / q}\right) - 1 \right]$$

Where I_o= Reverse Saturation Current n= Diode Ideality Factor K=Boltzmann's Constant T= Absolute Temperature q= Elementary Charge

For silicon of 25°C nkT/q=0.0259 volts= α

$$I_D = I_o \left[\exp\left(\frac{U + IR_s}{\alpha}\right) - 1 \right]$$



Reading is an adventure that never ends- Photo Voltaic Cell- Russell Ohl-1903





Substituting above equation in equation (1) we get

$$I = I_L - I_o \left[\exp\left(\frac{U + IR_s}{\alpha}\right) - 1 \right] - - - -(2)$$

Where $\alpha = nkT/q$ is known as Thermal Voltage Timing Completion Factor

The four Parameters I_L, I_o, R_s and α need to be determined to Study the I-U characteristics of PV cells





Believing in yourself is the first step to success- Lead Acid Battery- Raymond Gaston Plante-1859





LIGHT CURRENT ${\rm I_L}$ determination

$$I_{L} = \frac{\phi}{\phi_{ref}} \Big[I_{L,ref} + \mu_{I,SC} \Big(T_{c} - T_{c,ref} \Big) \Big]$$

Where ϕ = irradiance(W/m²)

 ϕ_{ref} = reference irradiance(1000 W/m² is used in this study)

 $I_{L,ref}$ = Light current at reference condition (1000 W/m² and 25 ^{0}c)

$$\Gamma_{\rm c} = PV$$
 cell temperature

 $T_{c,ref}$ = Reference Temperature (25^o C is used here)

 $\mu_{I,SC}$ = Temperature coefficient of the short circuit current (A/⁰C)

Both $I_{L,ref}$ and $\mu_{I,SC}$ can be obtained from manufacturer data sheet





Look at your strengths and not your weaknesses- SCR-General Electric (GE)-1958





PHOTOVOLTAIC CELL MODELING Cont...



SATURATION CURRENT I_0 determination

$$I_{o} = I_{o,ref} \left(\frac{T_{c,ref} + 273}{T_{c} + 273} \right)^{3} \exp \left[\frac{e_{gap} N_{s}}{q \alpha_{ref}} \left(1 - \frac{T_{c,ref} + 273}{T_{c} + 273} \right) \right]$$

Where $I_{o,ref}$ = Saturation current at the reference condition (A)

 e_{gap} = Band gap of the material (1.17eV for Si materials)

$$N_s$$
 = Number of cells in series of the PV module

q = Charge of the electron
$$(1.60217733 \times 10^{-19} C)$$

 $\alpha_{\rm ref}$ = The value of α at the reference condition

$$I_{o,ref} = I_{L,ref} \exp\left(-\frac{U_{oc,ref}}{\alpha_{ref}}\right)$$

 $U_{oc,ref}$ = The open circuit voltage of the PV module

at the reference condition(V) (Will be provided by manufacturers)



Success is a journey, Which has no Destination- Alternator-Nikola Tesla-1891







Calculation of α

$$\alpha_{ref} = \frac{2U_{mp,ref} - U_{oc,ref}}{\frac{I_{sc,ref}}{I_{sc,ref} - I_{mp,ref}} + \ln\left(1 - \frac{I_{mp,ref}}{I_{sc,ref}}\right)}$$

Where

 $U_{mp,ref} = \text{Maximum power point voltage at the reference condition (V)}$ $I_{mp,ref} = \text{Maximum power point current at the reference condition (A)}$ $I_{sc,ref} = \text{Short circuit current at the reference condition (A)}$

 α is a function of temperature, which is expressed as

$$\alpha = \frac{T_c + 273}{T_{c,ref} + 273} \alpha_{ref}$$



There is no age bar for learning- Electric Chair-Harold P.Brown-1888





PHOTOVOLTAIC CELL MODELING Cont...



Calculation of Series Resistance $\rm R_{s}$

Some manufactures provide value of $\mathsf{R}_{\mathsf{s},\mathsf{i}}$ if they do not provide It can be calculated as follows

$$R_{s} = \frac{\alpha_{ref} \ln\left(1 - \frac{I_{mp,ref}}{I_{sc,ref}}\right) + U_{oc,ref} - U_{mp,ref}}{I_{mp,ref}}$$

 R_s is taken as constant here Thermal Model of Photovoltaic cell

$$C_{pv} \frac{dT_c}{dt} = k_{in, pv} \phi - \frac{U \times I}{A} - K_{loss} \left(T_c - T_a\right)$$

 C_{pv} = The oveall heat capacity per unit area of the PV cell/Modul e [J/($^{0}c.m^{2}$)]

- $K_{in,pv}$ = Transmitta nce absorbtion product of PV cells
- k_{loss} = Overall heat loss coefficien t[W/($^{0}c.m^{2}$)]
- T_a = Ambient te mperature(${}^{0}c$)
- A = Effective area of the PVcell/ Module(m²)









PHOTOVOLTAIC CELL MODEL PARAMETERS



$I_{L,ref}(I_{SC},ref})$	2.664 A
α_{ref}	5.472 V
R _s	1.324 Ω
U _{oc,ref}	87.72 V
U _{mp,ref}	70.731 V
I _{mp,ref}	2.448 A
Φ _{ref}	1000 W/m ²
T _{c,ref}	25 ⁰ c

C _{PV}	5 X 10 ⁴ J/ (⁰ c.m ²)
А	1.5m ²
K _{in,pv}	0.9
K _{loss}	30 W/ (ºc.m²)



Present life is better than life coming in future – Robot- Jacques de Vaucanson-1738













Be willing to accept temporary inconvenience for permanent improvement –Dynamo-Michael Faraday-1832



PHOTOVOLTAIC CELL MODEL IN MATLAB/SIMULINK





🙀 Block Parameters: P¥ CELL MODEL	×
Photovoltaic cell (mask)	
Complete model of Photovoltaic cell Developed by Kaliamoorthy and Team	
Parameters	
Reference Temperature in degree centigrades	
Reference Irradiance	
1000	
Overall Heat Loss Coefficient(W/Cm2)	
30	
Number of cells in series	
153	
Timing factor at reference Condition(Alpha_ref)	
5.472	
Transmittance AbsorptionTransmittance Absorption	
Effective Area of the PV cell/Module(m2)	
Uver all heat capacity / unit area/Module	
Carina Desintanan	
1 324	
	-
OK Cancel Help Apply	



Better safe than sorry –Analog Storage Oscilloscope- Hughes-1957





CHARACTERISTICS OF PV CELL AT CONSTANT CELL TEMPERATURE









Distance lends enchantment to the view -CRO- Karl Ferdinand Braun- 1897



CHARACTERISTICS OF PV CELL AT CONSTANT IRRADIANCE







Everyone wants to go to heaven but nobody wants to die - Megger - Evershed - 1905

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Operation of Five Level Inverter with Auxiliary Switch







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Operation of Five Level Inverter with Auxiliary Switch







9	2	2	2	2	V
3 ₂	53	54	35	56	v inv
ON	OFF	OFF	OFF	ON	$+V_{p_{1}}/2$
OFF	ON	OFF	OFF	ON	$+V_{pv}$
	OFF	OFF	ON	ON	
OFF	or	or	or	or	0
	(ON)	(ON)	(OFF)	(OFF)	
ON	OFF	OFF	ON	OFF	$-V_{pv}/2$
OFF	OFF	ON	ON	OFF	$-V_{pv}$





History repeats itself - Electrolytic capacitor- Julius Edgar-1928



Comparison of Different Carrier Waves







New Five Level Inverter with Auxiliary Switch-**A dual Reference Modulation Technique**









PWM Strategy and Operating Principle



Modulation index Ma for five-level PWM inverter is given as

$$M_a = \frac{A_m}{2A_c}$$

Where Ac is the peak-to-peak value of carrier and Am is the peak value of voltage reference V_{ref} . Since in this work two reference signals identical to each other are used, above equation can be expressed in terms of amplitude of carrier signal V_c by replacing A_c with V_c and A_m=V_{ref1}=V_{ref2}=V_{ref}

$$M = \frac{V_{ref}}{2V_c}$$







PWM Strategy and Operating Principle





Switches S2–S4 will be switching at the rate of the carrier signal frequency, while S5 and S6 will operate at a frequency equivalent to the fundamental frequency.

A great talker is a great liar - Hall Effect- Edwin Hall -1879





CLOSED LOOP CONTROL SYSTEM







Maximum Power Point Algorithm









SIMULATION RESULTS





Dual Reference and Carrier Comparison





SIMULATION RESULTS





Switching Signals to S2 and S3













Switching Signals to S4 and S5





SIMULATION RESULTS





Switching Signals to S6





SIMULATION RESULTS



0.08



OUTPUT VOLTAGE WITH M ,D < 0.5

INVETER CURRENT WITH M ,D < 0.5





SIMULATION RESULTS





OUTPUT VOLTAGE AND ITS FUNDAMENTAL WITH M ,D > 1.0 INVETER CURRENT WITH M ,D > 1.0





SIMULATION RESULTS





OUTPUT VOLTAGE AND ITS FUNDAMENTAL WITH 0.5 <M ,D > 1.0 INVETER CURRENT WITH M ,D > 1.0



Never put off until tomorrow what you can do today - Remote Control – Nikola Tesla-1898





SIMULATION RESULTS



With out filters

Harmonic Spectrum of Voltage With 0.5 <M ,D > 1.0 Harmonic Spectrum of Current With 0.5 <M ,D > 1.0 Without filters







This paper presented a single-phase five-level inverter with a dual reference modulation technique for PV application. The dual reference modulation technique involves comparing two reference signals identical to each other except for an offset equivalent to its carrier signal, with a rectified inverted sine carrier signal to generate PWM switching signals for the switches. The circuit topology, control algorithm and operational principle of the proposed inverter were analyzed in detail. The results show that the THD of the five-level inverter is much less than that of the conventional three-level inverter. Furthermore, both the grid voltage and the grid current are in phase at near unity power factor.





Opportunity never knocks twice at any man's door - Electron – Joseph John – Thomson-1897.



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